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Influence of Cationic Ordering on the Lattice Dynamics of Monoclinic Cu5Sn2S7 and Cubic Cu5Sn2S6.65Cl0.35 Sulfides

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ABSTRACT: Cu2SnS3 is the parent compound of a series of phases in the Cu2+xSn1-xS3 section (0 ≤ x ≤ 0.15) of the ternary Cu−Sn−S phase diagram, the crystal structure of which can be controlled by varying the synthesis process and/or through a fine-tuning of the chemical composition. Despite being structurally close to the sphalerite structure, the thermal transport of these compounds is strongly dependent on the exact lattice symmetry and degree of atomic disorder. Here, we investigate the lattice dynamics of the monoclinic ordered Cu5Sn2S7 (space group C2) and cubic disordered Cu5Sn2S6.65Cl0.35 (space group $F43m$) compounds by temperaturedependent

powder inelastic neutron scattering (INS). In both cases, the INS spectra feature lowenergy optical modes mostly weighed by the thermal motion of Cu atoms. The response of the INS spectra of Cu5Sn2S6.65Cl0.35 to temperature variations is indicative of quasi-harmonic behavior. Combined with analyses of the low-temperature specific heat, these findings show that the significant lowering of the lattice thermal conductivity in cubic Cu5Sn2S6.65Cl0.35 is due to a reduced

phonon mean free path tied to the increased level of disorder in the unit cell. These results highlight how the stabilization of highly symmetric, yet strongly disordered crystal structures akin to those observed in high-entropy

alloys, can lead to a drastic reduction in the heat transport, offering an effective approach to design high-performance thermoelectric sulfides.

1. INTRODUCTION

Designing highly efficient thermoelectric materials, which

enable to convert a temperature difference into electrical

power and vice versa, requires to meet a subtle balance

between electronic and thermal properties.1−5 The unusual

combination of good electronic and poor thermal properties

that must be achieved is quantitatively captured by the

dimensionless thermoelectric figure of merit $ZT =$ α 2 T/ρ (Kel +

 kL) where T is the absolute temperature, α is the thermopower

(or Seebeck coefficient), ρ is the electrical resistivity and Kel

and κL are the electronic and lattice thermal conductivity,

respectively.1,2 In addition to conventional doping, common

strategies for the optimization of α , ρ and κ_{el} , all interdependent via the charge carrier concentration, usually

relies on band structure engineering that notably includes

resonant levels, band convergence, energy filtering effects or

the insertion of magnetic ions.6−17 Specific crystallographic

characteristics, such as loosely bound atoms in oversized cages

or tunnels,18−21 rotational degrees of freedom of polyhedra or

molecules,22−24 lone-pair-driven atomic offcentering,25−30

nanostructuration,31−33 or formation of solid solutions,_{1,2} are

various approaches that have been demonstrated to be effective

in lowering κ _L by either inducing dynamic disorder or

enhancing static disorder.

Copper-based sulfides, made of abundant and environmentally

friendly elements, provide a prominent example of the latter approach where a fine control of the level of static

disorder has been achieved through the optimization of the

sintering conditions or variations in the chemical composition. 34−38 Among them, the interest in the Cu−Sn−S system has been recently revitalized by the discovery of several phases, closely related to the mohite monoclinic phase Cu2SnS3.37−42 The heterovalency of Cu−Sn substitution leads to various structural types derived from the sphalerite cubic structure. In the series Cu2+xSn1−xS3, cubic, tetragonal and monoclinic crystal structures have been reported,41−47 wherein both the lattice symmetry and cationic disorder can be controlled by varying the Cu-to-Sn ratio. The change in the lattice symmetry by continuously increasing x up to 0.15 is accompanied by an increased metallic character of transport.⁴¹ Recently, the partial substitution of Cl for S in monoclinic Cu₅Sn₂S₇ was shown to stabilize a highly disordered cubic structure, 48 providing Received: May 27, 2024 Revised: July 25, 2024 Accepted: July 25, 2024 Published: August 8, 2024 pubs.acs.org/JPCC © 2024 American Chemical Society 14075 https://doi.org/10.1021/acs.jpcc.4c03489 J. Phys. Chem. C 2024, 128, 14075−14084 Downloaded via CEA SACLAY on November 5, 2024 at 09:46:21 (UTC). See https://pubs.acs.org/sharingguidelines for options on how to legitimately share published articles. another strategy to maintain the conductive sphalerite network while concomitantly lowering κι. Interestingly, this cubic polymorph exhibits improved electronic properties due to optimized carrier concentration and, most remarkably, lower κι compared to its monoclinic parent compound.⁴⁸ Probing their lattice dynamics may thus help to determine whether the strong local chemical disorder in the unit cell of the Cl-doped compound is the main mechanism driving the reduction in the phonon transport. Here, we investigate the lattice dynamics of the monoclinic

ordered sulfide Cu5Sn2S7 and the cubic disordered polymorph Cu5Sn2S6.65Cl0.35 by temperature-dependent powder inelastic neutron scattering (INS). The generalized vibrational density of states (GVDOS) inferred from these measurements is hardly influenced by the lattice symmetry. The temperature dependence of the GVDOS of the Cl-substituted polymorph follows a quasi-harmonic behavior, indicating that the distinct thermal transport between these two compounds is primarily tied to the strong degree of disorder in the cubic lattice, similar to what has been observed in colusites.49 These observations confirm that controlling the disorder of the cationic sublattice in sulfides is an effective strategy to lower K_{ph} , thereby contributing to improving their thermoelectric performance at high temperatures. 2. EXPERIMENTAL METHODS 2.1. Synthesis, Structural and Chemical Characterizations. Polycrystalline samples of Cu2SnS3, Cu5.133Sn1.866S7 and CusSn2S6.65Cl0.35 were prepared from pure elements Cu (99%), Sn (99.85%), S (99.5%) and CuCl (99%), all purchased from Alfa Aesar, in sealed silica tubes. All sample preparations and handlings were carried out in an Ar-filled glovebox. Cu5Sn2S6.65Cl0.35 was synthesized from the precursor Cu2SnS3, prepared from stoichiometric quantities of powdered Cu, Sn and S that were cold-pressed into a cylindrical pellet. The pellet was sealed in an evacuated silica tube, heated to 1023 K at a rate of 50 K h−1, dwelt at that

temperature for 48 h

before being cooled to room temperature at the same rate. The

as-prepared powder of Cu2SnS₃ was then used to prepare

Cu5Sn2S6.65Cl0.35 using additional amounts of Cu, Sn and CuCl

to adjust the stoichiometry. The mixtures were cold-pressed

and then heated to 873 K for 24 h with an intermediate step at 673 K for 12 h. The obtained powders were ground and sieved down to 200 μ m to avoid the presence of large agglomerates. Cu5Sn2S7 was prepared by mechanical alloying following the route described in our prior study.⁴¹ For transport properties and thermodynamic measurements, the powders were consolidated by spark plasma sintering (SPS, FCT HPD 25) in a graphite die of 10 mm diameter at 873 K for 30 min under a pressure of 64 MPa. The densities of the cylindrical dense pellets were higher than 99% of the theoretical densities calculated from X-ray diffraction data. X-ray powder diffraction (XRPD) data were collected at 300 K using a Bruker D8 advance Vario 1 two-circle diffractometer using the Cu K α_1 radiation (λ = 1.5406 A) and equipped with a Ge(111) monochromator (Johansson type) and a LynxEye detector. Rietveld refinements against the XRPD data were performed using the FullProf software.50 For temperaturedependent XRPD, data has been acquired in Debye−Scherrer geometry on a D8 advance diffractometer equipped with a Mo Kα radiation (selected by a focusing multilayer mirror), a set of radial Soller slits and a LynxEye HE detector. For the experiment, sieved powder has been sealed in an evacuated silica capillary (diameter of 0.3 mm) in order to avoid oxidation at high temperatures. Data were collected every 25 K from 300 to 800 K in the angular range $4^{\circ} \leq 2\vartheta \leq 1$ 35° with a step size of 0.0120°. The analysis of the diffraction patterns was performed using a parametric approach as implemented in TOPAS-Academic code.⁵¹ Transmission electron microscopy (TEM) experiments, including selected area electron diffraction (SAED), highangle

annular dark-field scanning TEM (HAADF-STEM), and energy-dispersive X-ray (EDX) STEM studies, were performed on a double aberration-corrected JEOL ARM200F cold FEG microscope operated at 200 kV and equipped with a CENTURIO large-angle EDX detector, an ORIUS CCD camera, and a Quantum GIF. Samples were prepared by crushing the materials in an agate mortar in ethanol and depositing the prepared suspension on a Ni holey carbon grid. The short-range ordering model was created using CristaKit software, and the simulation of the SAED pattern was performed using the MacTempas program. 2.2. Thermal Conductivity and Specific Heat Measurements. Thermal conductivity was measured between 2 and 300 K using the thermal transport option of a physical property measurement system (PPMS, Quantum Design). Barshaped samples with typical dimensions $2 \times 2 \times 8$ mm₃ were cut from the consolidated pellets with a diamondwire saw. Good electrical and thermal contacts were realized by attaching four copper leads onto the samples with a small amount of conductive silver epoxy. Specific heat C_p measurements were performed between 2 and 300 K on small pieces of the consolidated pellets using the dedicated option of the PPMS. Samples with a typical mass of 20 mg were mounted on the sample holder using a minute amount of Apiezon N grease, which gives rise to two small humps on the data between 200 and 300 K that correspond to the well-known phase transitions at ∼215 and ∼289 K. However, the use of this grease does not affect the accuracy of the data acquired at lower temperatures. 2.3. Inelastic Neutron Scattering Experiments. INS experiments (ref 52) were performed at the cold neutron timeofflight spectrometer SHARP, operated by the Laboratoire Léon Brillouin (LLB, Saclay, France), at the Institut Laue Langevin (ILL, Grenoble, France). All measurements were carried out in a cryofurnace under helium atmosphere with an incident neutron wavelength of 4.14 A. For each sample, about 15 g of powders were placed in a Nb cylindrical can. The data, collected at $T \approx 150$, 300, and 450 K, were corrected for empty sample holder scattering, for absorption, for frame overlap and self-attenuation and for different detector efficiencies of the multidetector bank using the Mantid software.53 Due to differences in total scattering powers $\sigma_t(\sigma_t = (\sigma_{coh} + \sigma_{inc})/M$ where σ_{coh} and σ_{inc} are the coherent and incoherent neutron cross sections expressed in barns, that is, 10−24 cm2 and M is the atomic mass) between Cu, Sn, S and Cl (0.126, 0.0412, 0.0320, and 0.474 barns/amu for Cu, Sn, S and Cl, respectively), 54 these measurements are more sensitive to Cu and Cl. The dynamic structure factors $S(Q,\omega)$ were calculated as an average signal over the scattering angle. The GVDOS $G(\omega)$ was derived within the incoherent approximation formalism. 55−58 All the spectra were normalized so that the integral of $G(\omega)$ is equal to the total number of phonon modes, that is 18 modes, for both samples (based on the general chemical formula Cu2+xSn1−xS3). Gaussian least-squares fits were used to The Journal of Physical Chemistry C pubs.acs.org/JPCC Article https://doi.org/10.1021/acs.jpcc.4c03489 J. Phys. Chem. C 2024, 128, 14075−14084 14076 approximate the position of the lowest-energy peak in $G(\omega)$. Only the inelastic signal at the anti-Stokes line was analyzed due to the limited energy range accessible at the Stokes line at

SHARP.

3. RESULTS AND DISCUSSION

3.1. Phase Purity and Crystal Structure. Crystal structure representations, XRPD patterns and HAADFSTEM

images of ordered monoclinic sulfide CusSn2S7 and its cubic disordered polymorph of nominal composition

Cu5Sn2S6.65Cl0.35 are summarized in Figure 1. Details on

crystal structure analyses can be found in refs 41 and 48 for the

Cu5Sn2S7 and Cu5Sn2S6.65Cl0.35 compounds, respectively.

These measurements confirm that CusSn2S7 crystallizes in

the monoclinic C2 space group while the Cl-doped phase of

nominal composition Cu5Sn2S6.65Cl0.35 adopts a cubic sphalerite-

type structure (space group $F43m$) indicating a fully disordered cationic distribution in the sphalerite lattice and

leading to a crystallographic chemical composition of

Cu0.71Sn0.29S0.95Cl0.05. This composition-driven structural transition

is further corroborated by HAADF-STEM images (see

Figure 1) and their corresponding fast-Fourier transform

patterns evidencing the disordered cubic crystal structure

adopted by the Cl-doped compound. Traces of cubic

Figure 1. Crystal structure representations (left), XRPD patterns (center) and HAADF-STEM images with their corresponding electron diffraction

pattern (right) of monoclinic ordered sulfide CusSn2S7 (top) and its cubic disordered polymorph Cu5Sn2S6.65Cl0.35 (bottom).

Figure 2. (a) GVDOS $G(\omega)$ of monoclinic CusSn2S7 and cubic Cu5Sn2S6.65Cl0.35 determined from INS

measurements at 300 K. For both compounds, the spectra were normalized so that the integral of $G(\omega)$ corresponds to 18 phonon modes. (b) Debye plots $G(\omega)/\omega$ 2 for both

samples that stress the low-energy region of the $G(\omega)$ spectra.

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Article https://doi.org/10.1021/acs.jpcc.4c03489 J. Phys. Chem. C 2024, 128, 14075−14084 14077 Cu₂₂Sn₁₀S₃₂ (space group P43n) (ref 42) and orthorhombic

Cu²‑^αS (space group P41212) (ref 59) are observed as

secondary phases in the XRPD data of the CusSn2S7 and

Cu5Sn2S6.65Cl0.35 samples, respectively. Attempts to quantify the concentrations of these secondary phases are estimated to be ∼8 wt % (that is, ∼ 3.6 at. %) and ∼1 wt %, respectively, according to Rietveld refinements. We note, however, that the crystal structure of cubic Cu22Sn10S32 is very close to that of the main phase CusSn2S7 resulting in an important convolution of the main diffraction peaks. In the case of Cu²‑^αS in the Cu5Sn2S6.65Cl0.35 sample, the number and intensity of the observed diffraction peaks do not allow for an unambiguous determination of the structural model. For these reasons, the quantification of these impurities remains approximative and possibly overestimated in the case of Cu22Sn10S32. In any case, their presence is not expected to significantly affect the transport properties or the INS signal discussed hereafter. Temperature-dependent XRPD experiments further indicate the absence of structural phase transition between 300 and 800 K (Figure S1 in Supporting Information). 3.2. Powder Inelastic Neutron Scattering. Figure 2a shows a comparison of the generalized densities of states $G(\omega)$ of monoclinic Cu5Sn2S7 and cubic Cu5Sn2S6.65Cl0.35 inferred from INS measurements at 300 K. The measured $G(\omega)$ are very similar, with pronounced low-energy peaks observed at 7.6 and 8.2 meV for Cu5Sn2S6.65Cl0.35 and Cu5Sn2S7, respectively. These two peaks feature shoulders on either side, that are also visualized in the Debye plots $G(\omega)/\omega_2$ (Figure 2b). A second block of peaks is observed around 15 meV. The inelastic signal becomes less structured beyond this peak and up to about 27 meV where the third and last block of peaks centered at ∼31 meV can be distinguished. The phonon cutoff

energy of around 40 meV is consistent with lattice dynamics calculations predicting a cutoff frequency of ∼10 THz (∼41.3 meV).60 For monoclinic Cu5Sn2S7, the spectral distribution of the peaks, their characteristic energies and their relative intensities are similar to those reported for monoclinic Cu2SnS3 by lattice dynamics calculations.60 The comparison of these calculations with $G(\omega)$ indicates that the first two blocks are mostly weighed by Cu and Sn atoms while the peaks at higher energies mostly correspond to modes dominated by S atoms. A similar conclusion holds for cubic Cu5Sn2S6.65Cl0.35, with the presence of the small concentration of Cl hardly modifying the overall shape and characteristic energies of the first two blocks, while some differences can be observed above 20 meV. Optical modes mostly weighed by Cl are expected to dominate at high energies due to the similar molar mass of Cl with respect to S. The mode assignment and the presence of these low-energy peaks in both samples are consistent with nuclear inelastic scattering measurements of the partial GVDOS of Sn atoms performed on monoclinic CTSbased samples.60 To shed light on the anharmonicity of the Cu and Sndominated low-energy peaks, temperature-dependent INS spectra were measured on Cu5Sn2S6.65Cl0.35 (Figure 3). The experimental data collected at 150 K have been discarded above ∼20 meV due to the strongly reduced intensity, which is scaled by the Bose−Einstein occupation factor. The weak shift of the entire spectrum upon heating is consistent with a quasiharmonic behavior, indicating the absence of significant anharmonicity beyond the cubic term associated with the thermal expansion of the crystal lattice.

This variation, equally observed for the colusites Cu26V2Sn6S32,49 contrasts with that reported for the tetrahedrites

Cu₁₂Sb₄S₁₃ (refs 61 and 62.) and aikinite CuPbBiS₃ (ref

63) for which the lowest-energy peaks show the opposite

trend, that is a shift toward lower energy upon cooling,

characteristic of anharmonic behavior. The rate of change in

the characteristic energy of the main peaks can be well

accounted for by evaluating the volume dependence (V) of the

phonon mode energy E_i , quantified through the mode-specific

G r ün e i s e n p a r a m e t e r y i b y t h e r e l a t i o n

 $i=\left(\begin{array}{c} \end{array} \right) = \left(\begin{array}{c} \end{array} \right)$ E V T \dot{v} E E V T ln ln i i ⁱ.64 Within the quasiharmonic approximation, the thermodynamic averaged Grüneisen parameter G for all modes can be assumed and is related to Figure 3. (a) Temperature dependence of the GVDOS $G(\omega)$ of cubic CusSn2S6.65Cl0.35. (b) Corresponding Debye plots $G(\omega)/\omega$ ₂. The temperature- and color-coded symbols are reported in the figures. The Journal of Physical Chemistry C pubs.acs.org/JPCC Article https://doi.org/10.1021/acs.jpcc.4c03489 J. Phys. Chem. C 2024, 128, 14075−14084 14078 the average phonon energy $\langle E \rangle$ via the relation = E G V ln ln , equivalently rewritten as ε = E \overline{V} G V 0 0 . G can be expressed in terms of thermodynamic quantities, experimentally accessible, according to the relation = BV G C V V where V is the molar volume, Cv is the isochoric specific heat, B is the bulk modulus

and α ^v is the volumetric thermal expansion coefficient.⁶⁴ G has been calculated at 300 K using the measured C_p values and the B values inferred from measurements of the longitudinal and transverse sound velocities by a pulse-echo method (67 and 61 GPa for CusSn2S7 and CusSn2S6.65Cl0.35, respectively). For cubic Cu5Sn2S6.65Cl0.35, αV was determined from the linear thermal expansion coefficient measured by dilatometry and was found to be equal to 20.4 × 10−6 K−1 at 300 K. For monoclinic Cu₅Sn₂S₇, αν was determined through lattice parameter refinements of temperature-dependent XRPD patterns collected up to 800 K (Figure S2 in Supporting Information), yielding an average value of $31.6 \times$ 10−6 K−1 over the 300−500 K temperature range. Combining these values results in G of 1.10 and 0.65 for CusSn2S7 and Cu5Sn2S6.65Cl0.35, respectively. These two values are lower than those inferred for the sulfur-based synthetic colusite Cu26V2Sn6S32 (G 1.5−2 depending on the synthesis route)49 and several other strongly anharmonic compounds₆₅− 69 such as AgSbTe2 (G 2.05), 65 AgBi3S5 (ac 3.6, averaged only over the acoustic dispersions along the a, b and c crystallographic axes) 66 or CsAgsTe3 (ac 4.2, averaged only over the acoustic dispersions along the a, b and c crystallographic axes), 67 indicating that both Cu5Sn2S7 and Cu5Sn2S6.65Cl0.35 are weakly anharmonic. For Cu5Sn2S6.65Cl0.35, the quasiharmonic prediction of the temperature dependence of the characteristic energy of the lowest-energy peaks agrees reasonably well with that observed experimentally by INS (Figure 4). 3.3. Specific Heat. Figure 5 shows the temperature dependence of the specific heat C_p , plotted as C_p/T versus

T2, of the Cu5Sn2S7 and Cu5Sn2S6.65Cl0.35 samples. For

comparison, data measured on the parent compound Cu2SnS3 (space group Cc) and on the Cu-rich Cu5.133Sn1.866S7 composition (space group C2) have been added. The low-temperature data were fitted to the conventional free-electron gas formula = + T_c T $ρ$ 2 where $γ$ is the Sommerfeld coefficient corresponding to the electronic contribution and $6T_2$ is the lattice contribution. The parameter $β$ is related to the Debye temperature $θ$ _D by the relation $D = [(12 \text{ NR})/(5)]$ $41/3$ where R is the ideal gas constant and N is the number of atoms per formula unit. The best linear fit to the C_p/T versus T_2 data yields a *γ* value indistinguishable from zero to within experimental uncertainty for Cu2SnS3 and γ values of 7.45 } 0.10, 7.00 } 0.10 and 5.00 } 0.10 mJ mol−1 K−2 for the Cu5Sn2S7, Cu5.133Sn1.866S7 and Cu5Sn2S6.65Cl0.35 compounds, respectively. While the zero value of Cu2SnS3 is consistent with its nearly intrinsic semiconducting nature,41 the values inferred for these last three samples imply finite density of states at the Fermi level within a free-electron model, a finding consistent with the degenerate character of transport. 41,48 The β parameters correspond to Debye temperatures ϑ _D of 289 } 5, 268 } 5, 277 } 5 and 262 } 5 K for Cu2SnS3, Cu5Sn2S7, Cu5.133Sn1.866S7 and Cu5Sn2S6.65Cl0.35, respectively. For all samples, the lattice contribution to the specific heat, C_{ph}, determined by subtracting the electronic contribution to the C_p data, is characterized by a pronounced peak centered around 17 K, best visualized when the data are plotted as Cph/ T_3 versus T (Figure 6). In cage-like compounds such as type-I clathrates and skutterudites,70−75 this peak has been modeled

Figure 4. Temperature dependence of the characteristic energy (red filled circle symbols) of the low-energy peak near 7.5 meV for cubic Cu₅Sn₂S_{6.65}Cl_{0.35}, obtained from fits to the $G(\omega)/\omega$ ₂ data with Gaussian functions. The black solid line corresponds to the quasiharmonic (QH) prediction of the temperature dependence of this peak using a thermodynamic average Grüneisen parameter G of 0.65. Figure 5. Temperature dependence of the specific heat C_p of monoclinic Cu2SnS3 (space group Cc), CusSn2S7 (space group C2) and Cu5.133Sn1.866S7 (space group C2) and cubic Cu5Sn2S6.65Cl0.35 (space group $F43m$). The solid black lines highlight the T_2 range where the free-electron formula = $+ 7$ C T ^p2 is obeyed. The Journal of Physical Chemistry C pubs.acs.org/JPCC Article https://doi.org/10.1021/acs.jpcc.4c03489 J. Phys. Chem. C 2024, 128, 14075−14084 14079 by Einstein-like contributions reflecting the large thermal motion of encaged cations, providing a direct mean to extract the characteristic energies of the associated optical modes. Herein, we tried to extend this model, which describes the specific heat as a linear combination of a Debyeand two Einstein-like contributions according to the relation $C_p(T) = C_D(T) + C_{E1}(T) + C_{E2}(T)$ (1) where $C_D(T)$ and $C_{Ei}(T)$ are the lattice specific heat within the Debye approximation and the Einstein contribution of the localized oscillators *i*, respectively, given by $CT = N R T x e$ e $() 9 x$ (1) d T x $D D x$ D 3 0 / 4 $\overline{2}$ D i k jjjjj y {

zzzzz

when considering the chemical ille the value of ϑ _{E2} of ∼86 K valent for all samples, the ϑ_{E1} value es to values ranging between 46 the Cu5Sn2S7, Cu5.133Sn1.866S7 and Cu5Sn2S6.65Cl0.35 rrespond fairly well to the onset of inuum that was found to start near K) and ∼1.3 THz (~5.4 meV, ~63 ordered models of Cu2SnS3, calculations and 119Sn nuclear urements on ordered and $nS₃$ ed by high-energy ball-milling.⁶⁰ The for the disordered compounds may the optical modes to shift toward ncreasing the disorder in the unit ansport. The total thermal ic Cu2SnS3, Cu5Sn2S7 and oic CusSn2S6.65Cl0.35 differs ure nced Umklapp peak reaching ∼30 oristine Cu2SnS₃ is substantially longer visible in Cu5.133Sn1.866S7 and For Cu₅Sn₂S₇, κ rapidly increases ~15 W m−1 K−1 around 50 K, lecreasing to \sim 10 W m−1 K−1 at 300 ralues of the cubic polymorph are aximum of \sim 2.5 W m−1 K−1 that 300 K. These observations hold conductivity $\kappa_L = \kappa - \kappa_{el}$ determined electronic thermal conductivity κ_{el}

the Wiedemann–Franz law $\kappa_{el} = LT/\rho$, where L is the Lorenz number assumed to be equal to the degenerate limit $L_0 = 2.45$ × 10−8 V2 K−2 due to the degenerate character of transport in Cu5.133Sn1.866S7, Cu5Sn2S7 and Cu5Sn2S6.65Cl0.35.41,48 Because of the intrinsic semiconducting nature of Cu2SnS3, the heat transport is mainly mediated by phonons, making the approximation $\kappa \approx \kappa$ quasi exact in the present case. The difference in *κ*^L between Cu₅.133Sn_{1.866}S₇ and Cu5Sn2S6.65Cl0.35 (κL≈ 3.8 and 1.5 W m−1 K−1, respectively, at 300 K) cannot solely originate from mass fluctuations and size effects due to the similar molar masses and ionic radii of Cl− and S2− (181 and 184 pm, respectively). Rather, the strong decrease observed may be attributed to the scattering of acoustic phonons from force-constant fluctuations that accompany the strong local chemical disorder in the cubic unit cell of Cu5Sn2S6.65Cl0.35 and significantly shorten acoustic phonon lifetimes. This mechanism is qualitatively equivalent to that observed in more complex materials such as type-I clathrates or high-entropy alloys, even though acoustic phonons have been shown to remain well-defined over a large part of the Brillouin zone.76−78 In spite of the strong disorderinduced lowering of $κ$ ¹, none of the measured values approach the lower bound reached when the Ioffe-Regel limit for phonons is attained, that is, when the average phonon mean free path is nearly equivalent to the mean interatomic distance.79 This lower bound can be estimated from the hightemperature limit κglass of the formula derived by Cahill, Watson and Pohl for amorphous and strongly disordered compounds80 $= k V v + v 1$ 2 6 glass (2)

1/3 B 2/3 T L i k jjj y { zzz (4) where V is the average volume per atom and v_T and v_l are the transverse and longitudinal sound velocity, respectively. v_T and vL, measured at 300 K by a pulse-echo method, were found to be typically around 4550 and 2420 m s−1 for the monoclinic compounds and equal to 4720 and 2470 m s−1 for the cubic compound. These values lead to a lower bound of $\kappa_{\text{glass}} \sim 0.2$ W m-1 K-1 for the monoclinic and cubic polymorphs. Neither the ordered monoclinic nor the disordered cubic compounds approach this limit in this temperature range, suggesting room for further decreasing κ _L by enhancing mass fluctuations for instance. 4. CONCLUSIONS The lattice dynamics of the ordered monoclinic Cu5Sn2S7 and the disordered cubic Cu5Sn2S6.65Cl0.35 sulfides has been investigated by means of low-temperature thermal conductivity and specific heat measurements and temperaturedependent powder INS experiments. The generalized phonon density of states measured by INS exhibit low-energy peaks that are assigned to phonon modes mostly weighed by Cu atoms. Upon cooling, the characteristic energy of the peaks of the INS spectrum shifts, following a rate of change mainly determined by the thermal expansion of the unit cell. The analysis of the low-temperature specific heat and lattice thermal conductivity suggests that the stabilization of the cubic unit cell upon Cl doping enhances the disorder on the cationic sublattice. This

high degree of disorder in Cu5Sn2S6.65Cl0.35 appears to be the

main ingredient that drives the significant reduction in the lowtemperature

thermal conductivity observed experimentally. Successfully growing single crystals of ordered and disordered

Cu2SnS3 would be of interest to verify

experimentally the main

trait of the phonon dynamics suggested by these results, that is,

the disorder-induced shortening of acoustic phonon lifetimes.

In this regard, one possibility to further reduce the lattice

thermal conductivity in these disordered sulfides would be to

consider substitutions on the cationic sublattice with more

dissimilar elements to enhance the force-constant fluctuations

between neighboring atomic species.

■ ASSOCIATED CONTENT

* Supporting Information

.

The Supporting Information is available free of charge at

https://pubs.acs.org/doi/10.1021/acs.jpcc.4c03489

Thermal expansion coefficients for a monoclinic lattice,

high-temperature PXRD patterns of monoclinic Cu5Sn2S7, temperature-dependent XRD data of monoclinic Cu5Sn2S7 (PDF)

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J. Phys. Chem. C 2024, 128, 14075−14084

14084